

Tuning van der Waals heterostructures by pressure

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In van der Waals heterostructures the layer distance strongly affects the interaction between the layers. Therefore, pressure is an ideal tool to engineer the band structure of van der Waals materials [1].

Here we will show examples for the versatility of this method. First, I will show, how this allows the tunability of the band structure of multi-layer graphene and how in WSe₂/Gr structures spin-orbit coupling can be boosted using hydrostatic pressure [2]. Finally, I will demonstrate the band structure tuning of magic-angle twisted double bilayer graphene [3]. We have performed thermal activation and magneto-transport measurements to reveal changes in the bandgaps of the system. We have observed a strong tuneability with pressure, which is confirmed by our theoretical calculations. Finally, we have also observed changes in the strength of electron-electron interactions and in the topological phases at the charge neutrality point in magnetic fields.

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